

UNISONIC TECHNOLOGIES CO., LTD

MGBR40V45C

Preliminary

DIODE

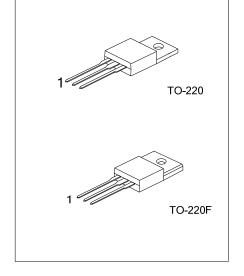
DUAL MOS GATED BARRIER RECTIFIER

DESCRIPTION

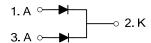
The UTC MGBR40V45C is a dual mos gated barrier rectifiers, it uses UT C's advanc ed tech nology to pro vide custom ers with lo w forward voltage drop and high switching speed, etc.

FEATURES

- * Very low forward voltage drop
- * High switching speed



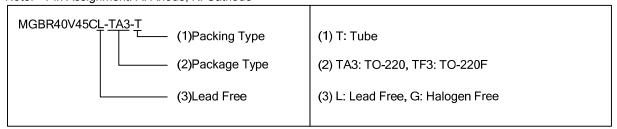
SYMBOL



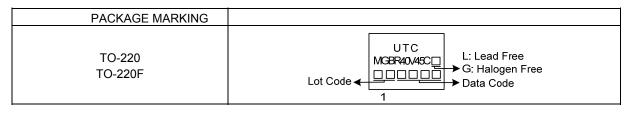
ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR40V45CL-TA3-T	MGBR40V45CG-TA3-T	TO-220	Α	K	Α	Tube	
MGBR40V45CL-TF3-T	MGBR40V45CG-TF3-T	TO-220F	Α	K	Α	Tube	

Note: Pin Assignment: A: Anode, K: Cathode



MARKING INFORMATION



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■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER SYMBOL			RATINGS	UNIT
DC Blocking Voltage		V _{RM} 45		V
Working Peak Reverse Voltage		V _{RWM} 45		V
Peak Repetitive Reverse Voltage		V _{RRM} 45		V
Average Restified Output Current Per Device	Per Leg	-	20 A	
Average Rectified Output Current Per Device	Total 4	IO	0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM} 280		Α
Operating Junction Temperature		T _J -65~	+150	°C
Storage Temperature		T _{STG} -65	+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS (PER LEG)

PARAMETER SYMBOL		RATINGS	UNIT
Junction to Case	θ _{JC} 2		°C/W

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	I _R =0.50mA 45				V
Forward Voltage Drop	V _{FM}	I _F =20A, T _J =25°C			0.55	٧
		I _F =20A, T _J =125°C			0.50	V
Leakage Current (Note 1)	I I I I I I I I I I I I I I I I I I I	V _R =45V, T _J =25°C			500	μΑ
		V _R =45V, T _J =125°C			100	mΑ

Notes: 1. Short duration pulse test used to minimize self-heating effect.

^{2.} Thermal resistance junction to case mounted on heatsink.

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